

EN: This Datasheet is presented by the manufacturer.

Please visit our website for pricing and availability at www.hestore.hu.

SWITCHMODE TM **Power Rectifiers**

These state-of-the-art devices are a series designed for use in switching power supplies, inverters and as free wheeling diodes.

Features

- Ultrafast 35 and 60 Nanosecond Recovery Times
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- High Temperature Glass Passivated Junction
- High Voltage Capability to 600 V
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating @ Both Case and Ambient Temperatures
- Pb-Free Packages are Available*

Mechanical Characteristics:

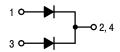
- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



ON Semiconductor®

http://onsemi.com

ULTRAFAST RECTIFIERS 16 AMPERES, 100-600 VOLTS





TO-220AB CASE 221A **PLASTIC**

MARKING DIAGRAM



= Assembly Location Α

= Year WW = Work Week U16xx = Device Code

G

xx = 10, 15, 20, 40 or 60= Pb-Free Package KA = Diode Polarity

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

		MUR16					
Rating	Symbol	10CT	15CT	20CT	40CT	60CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	150	200	400	600	V
Average Rectified Forward Current Per Leg Total Device, (Rated V_R), $T_C = 150$ °C Total Device	. (/ (* /			8.0 16			Α
Peak Rectified Forward Current Per Diode Leg (Rated V _R , Square Wave, 20 kHz), T _C = 150°C	I _{FM}			16			Α
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}			100			Α
Operating Junction Temperature and Storage Temperature	T _J , T _{stg}		_	65 to +1	75		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS (Per Diode Leg)

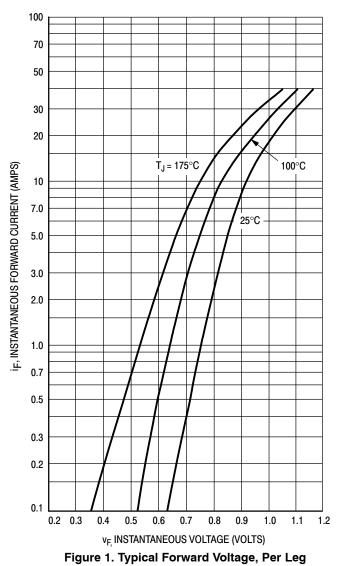
Parameter	Symbol	Value		Unit
Maximum Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	3.0	2.0	°C/W

ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Characteristic	Symbol	1620	1640	1660	Unit
Maximum Instantaneous Forward Voltage (Note 1) (iF = 8.0 A, T_C = 150°C) (iF = 8.0 A, T_C = 25°C)	VF	0.895 0.975	1.00 1.30	1.20 1.50	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, T_C = 150°C) (Rated DC Voltage, T_C = 25°C)	İR	250 5.0		00	μΑ
Maximum Reverse Recovery Time ($I_F = 1.0 \text{ A}$, $I_R = 0.25 \text{ A}$)	t _{rr}	35 25	6 5	0	ns

^{1.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%

MUR1610CT, MUR1615CT, MUR1620CT



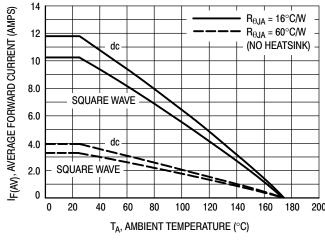


Figure 4. Current Derating, Ambient, Per Leg

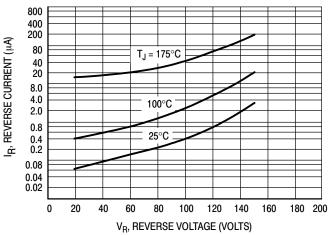


Figure 2. Typical Reverse Current, Per Leg*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R .

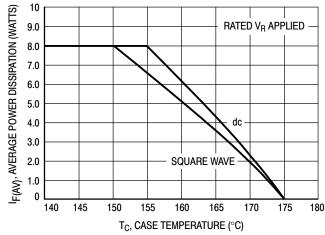


Figure 3. Current Derating, Case, Per Leg

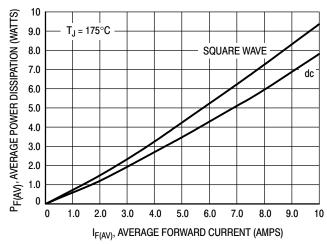


Figure 5. Power Dissipation, Per Leg

MUR1640CT

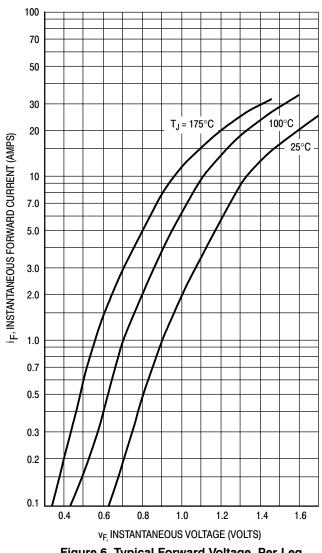


Figure 6. Typical Forward Voltage, Per Leg

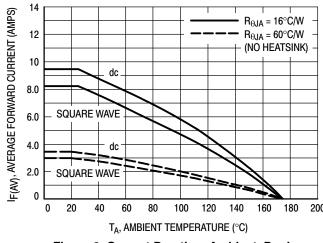


Figure 9. Current Derating, Ambient, Per Leg

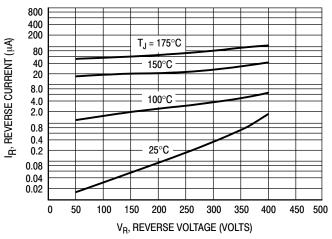


Figure 7. Typical Reverse Current, Per Leg*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these curves if $V_{\mbox{\scriptsize R}}$ is sufficiently below rated V_R .

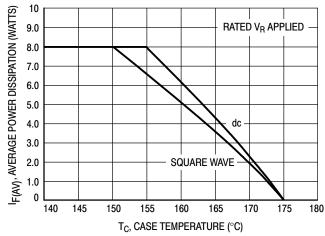


Figure 8. Current Derating, Case, Per Leg

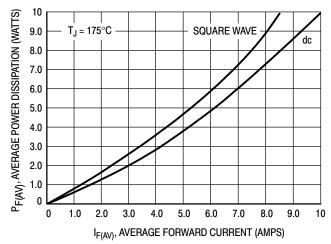


Figure 10. Power Dissipation, Per Leg

MUR1660CT

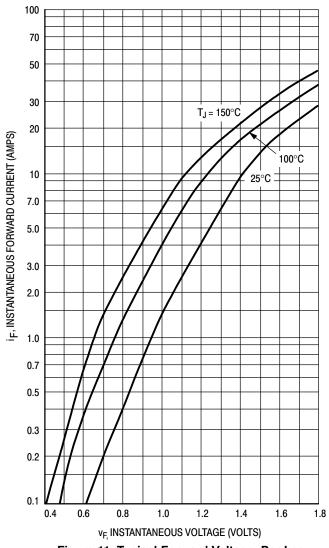


Figure 11. Typical Forward Voltage, Per Leg

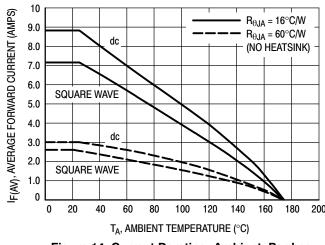


Figure 14. Current Derating, Ambient, Per Leg

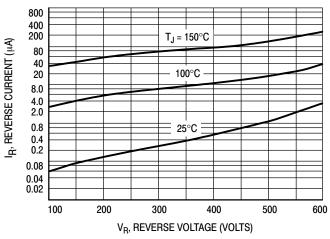


Figure 12. Typical Reverse Current, Per Leg*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if $V_{\mbox{\scriptsize R}}$ is sufficiently below rated V_R.

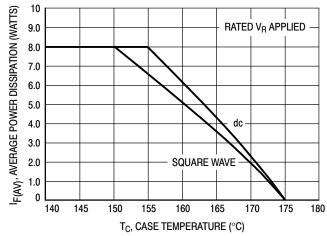


Figure 13. Current Derating, Case, Per Leg

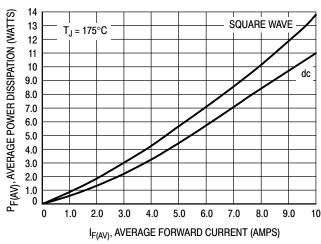


Figure 15. Power Dissipation, Per Leg

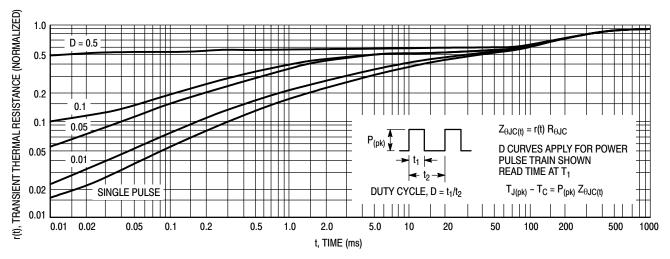


Figure 16. Thermal Response

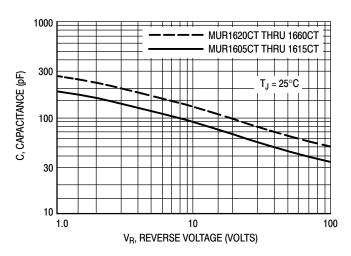


Figure 17. Typical Capacitance, Per Leg

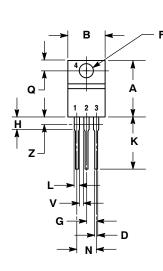
ORDERING INFORMATION

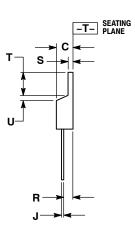
Device	Package	Shipping [†]
MUR1610CT	TO-220	
MUR1610CTG	TO-220 (Pb-Free)	
MUR1615CT	TO-220	
MUR1615CTG	TO-220 (Pb-Free)	
MUR1620CT	TO-220	
MUR1620CTG	TO-220 (Pb-Free)	50 Units / Rail
MUR1640CT	TO-220	
MUR1640CTG	TO-220 (Pb-Free)	
MUR1660CT	TO-220	
MUR1660CTG	TO-220 (Pb-Free)	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AF**





- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.161	3.61	4.09	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.014	0.025	0.36	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
T	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

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